

## TC1041

# **Linear Building Block – Dual Low Power Comparator and Voltage Reference with Programmable Hysteresis**

#### **Features**

- Combines Two Comparators and a Voltage Reference in a Single Package
- · Optimized for Single Supply Operation
- Available in Two Small Packages: 8-Pin SOIC or 8-Pin MSOP
- Ultra Low Input Bias Current: Less than 100pA
- Low Quiescent Current, Operating: 10μA (Typ.)
- · Rail-to-Rail Inputs and Outputs
- Operates Down to V<sub>DD</sub> = 1.8V
- · Programmable Hysteresis

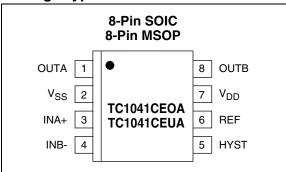
## **Applications**

- · Power Supply Circuits
- Battery Operated Equipment
- · Consumer Products
- · Replacements for Discrete Components

#### **Device Selection Table**

Part Number	Package	Temperature Range		
TC1041CEOA	8-Pin SOIC	-40°C to +85°C		
TC1041CEUA	8-Pin MSOP	-40°C to +85°C		

**Package Types** 



### **General Description**

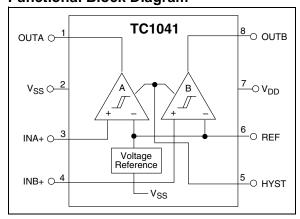
The TC1041 is a mixed-function device combining two comparators and a voltage reference in a single 8-pin package. The inverting inputs of both comparators are internally connected to the reference.

This increased integration allows the user to replace two packages, which saves space, lowers supply current and increases system performance. The TC1041 operates from two 1.5V alkaline cells down to  $V_{DD}=1.8V$ . It requires only  $10\mu A$  typical supply current which significantly extends battery life. The TC1041 provides a simple method for adding user-adjustable hysteresis without feedback or complex external circuitry. Hysteresis is adjusted with a simple resistor divider on the HYST pin.

Rail-to-rail inputs and outputs allow operation from low supply voltages with large input and output signal swings.

Packaged in an 8-Pin SOIC or 8-Pin MSOP, the TC1041 is ideal for applications requiring low power and small packages.

## **Functional Block Diagram**



## 1.0 ELECTRICAL CHARACTERISTICS

## **ABSOLUTE MAXIMUM RATINGS\***

 \*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

### **TC1041 ELECTRICAL SPECIFICATIONS**

Symbol	Parameter	Min	Тур	Max	Units	Test Conditions
$V_{DD}$	Supply Voltage	1.8	_	5.5	V	
IQ	Supply Current Operating	_	10	15	μΑ	All Outputs Open
Comparator	S					
V <sub>IR</sub>	IN+ Voltage Range	V <sub>SS</sub> - 0.2	_	V <sub>DD</sub> + 0.2	V	
V <sub>OS</sub>	Input Offset Voltage	-5 -5	_	+5 +5	mV mV	V <sub>DD</sub> = 3V, T <sub>A</sub> = 25°C T <sub>A</sub> = -40°C to 85°C <b>(Note 1)</b>
I <sub>B</sub>	Input Bias Current	_	_	±100	pA	$T_A = 25$ °C, IN+ = $V_{DD}$ to $V_{SS}$
V <sub>OH</sub>	Output High Voltage	V <sub>DD</sub> - 0.3	_	_	V	$R_L = 10k\Omega$ to $V_{SS}$
V <sub>OL</sub>	Output Low Voltage	_	_	0.3	V	$R_L = 10k\Omega$ to $V_{DD}$
CMRR	Common Mode Rejection Ratio	66	_	_	dB	$T_A = 25$ °C, $V_{DD} = 5V$ $V_{CM} = V_{DD}$ to $V_{SS}$
PSRR	Power Supply Rejection Ratio	60	_	_	dB	T <sub>A</sub> = 25°C V <sub>DD</sub> = 1.8V to 5V
I <sub>SRC</sub>	Output Source Current	1	_	_	mA	$IN+ = V_{DD},$ Output Shorted to $V_{SS}$ $V_{DD} = 1.8V$
I <sub>SINK</sub>	Output Sink Current	2	_	_	mA	$IN+ = V_{SS},$ Output Shorted to $V_{DD}$ $V_{DD} = 1.8V$
V <sub>HYST</sub>	Voltage Range at HYST Pin	V <sub>REF</sub> - 0.08	_	V <sub>REF</sub>	V	
I <sub>HYST</sub>	Hysteresis Input Current	_	_	±100	nA	
t <sub>PD1</sub>	Response Time	_	4	_	μsec	100mV Overdrive, C <sub>L</sub> = 100pF
t <sub>PD2</sub>	Response Time	_	6	_	μsec	10mV Overdrive, C <sub>L</sub> = 100pF
Voltage Refe	rence					
V <sub>REF</sub>	Reference Voltage	1.176	1.200	1.224	V	
I <sub>REF(SOURCE)</sub>	Source Current	50			μΑ	
I <sub>REF(SINK)</sub>	Sink Current	50		_	μΑ	
C <sub>L(REF)</sub>	Load Capacitance	_	_	100	pF	
E <sub>VREF</sub>	Noise Voltage	_	20	_	$\mu V_{RMS}$	100Hz to 100kHz
e <sub>VREF</sub>	Noise Voltage Density		1.0	_	μV/√Hz	1kHz

Note 1: V<sub>OS</sub> is measured as (V<sub>UT</sub> + V<sub>LT</sub> - 2V<sub>REF</sub>)/2 where V<sub>UT</sub> is the upper hysteresis threshold and V<sub>LT</sub> is the lower hysteresis threshold with V<sub>REF</sub> - V<sub>HYST</sub> set to 10mV. This represents the assymetry of the hysteresis thresholds around V<sub>REF</sub>

## 2.0 PIN DESCRIPTION

The description of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

Pin No. (8-Pin SOIC) (8-Pin MSOP)	Symbol	Description
1	OUTA	Comparator output.
2	V <sub>SS</sub>	Negative power supply.
3	INA+	Non-inverting input to Comparator A.
4	INB-	Non-Inverting input to Comparator B.
5	HYST	Adjustable hysteresis input.
6	REF	Voltage reference output.
7	V <sub>DD</sub>	Positive power supply.
8	OUTB	Comparator output.

## 3.0 DETAILED DESCRIPTION

The TC1041 is one of a series of very low power, linear building block products targeted at low voltage operation. The TC1041 contains two comparators and a voltage reference and operates at a minimum supply voltage of 1.8V with a typical current consumption of  $10\mu A$ . Both comparators have programmable hysteresis.

## 3.1 Comparator

The TC1041 contains two comparators with programmable hysteresis. The inverting inputs of the comparators are connected to the output of the voltage reference, while the range of the non-inverting inputs extend beyond both supply voltages by 200mV. The comparator outputs will swing to within several millivolts of the supplies depending on the load current being driven.

The comparators exhibit a propagation delay and supply current which are largely independent of supply voltage. The low input bias current and offset voltage make them suitable for high impedance precision applications.

## 3.2 Voltage Reference

A 2.0 percent tolerance, internally biased, 1.20V bandgap voltage reference is included in the TC1041. It has a push-pull output capable of sourcing and sinking at least 50µA.

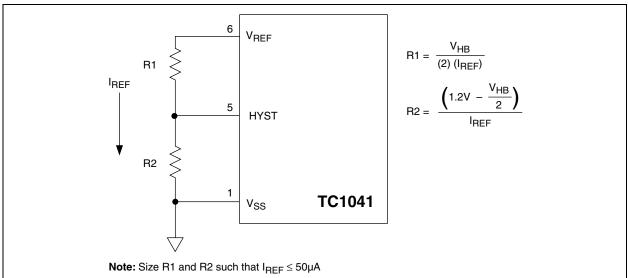
## 3.3 Programmable Hysteresis

Hysteresis is added to the comparators by connecting a resistor, R1, between the  $V_{REF}$  and HYST pins and another resistor, R2, between the HYST pin and  $V_{SS}$ . For no hysteresis,  $V_{REF}$  should be directly connected to HYST. The hysteresis,  $V_{HB}$ , is equal to twice the voltage difference between the  $V_{REF}$  and HYST pins where:

$$V_{HB} = 2V_{REF} R1/(R1 + R2)$$
 (See Figure 3-1)

and is symmetrical around the normal (without hysterersis) threshold of the comparator. The maximum voltage allowed between the  $V_{REF}$  and  $H_{YST}$  pins is 80mV, giving a maximum hysteresis of 160mV.

FIGURE 3-1: TC1041 PROGRAMMABLE HYSTERESIS



## 4.0 TYPICAL APPLICATIONS

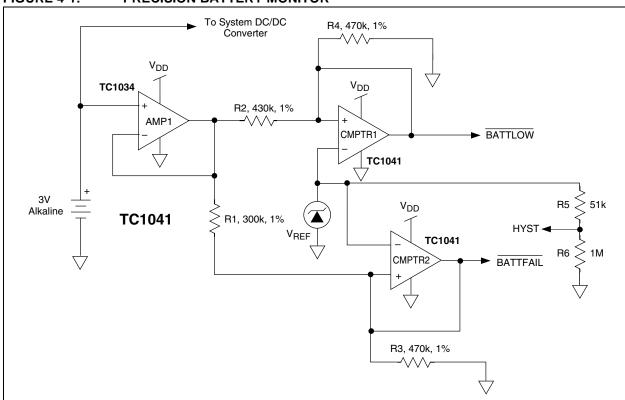
The TC1041 lends itself to a wide variety of applications, particularly in battery powered systems. It typically finds application in power management, processor supervisory and interface circuitry.

## 4.1 Precision Battery Monitor

Figure 4-1 is a precision battery low/battery dead monitoring circuit. Typically, the battery low output warns the user that a battery dead condition is imminent. Battery dead typically initiates a forced shutdown to prevent operation at low internal supply voltages (which can cause unstable system operation).

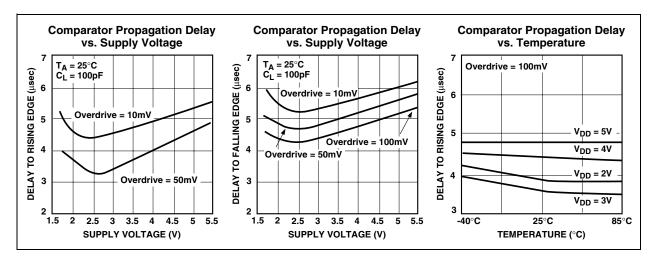
The circuit in Figure 4-1 uses a TC1034, a TC1041 and only six external resistors. AMP 1 is a simple buffer while CMPTR1 and CMPTR2 provide precision voltage detection using  $V_{REF}$  as a reference. Resistors R2 and R4 set the detection threshold for  $\overline{BATT}$  LOW while Resistors R1 and R3 set the detection threshold for  $\overline{BATT}$  FAIL. The component values shown assert  $\overline{BATT}$  LOW at 2.2V (typical) and  $\overline{BATT}$  FAIL at 2.0V (typical). Total current consumed by this circuit is typically 16 $\mu$ A at 3V. Resistors R5 and R6 provide hysteresis of 116mV for both comparators.

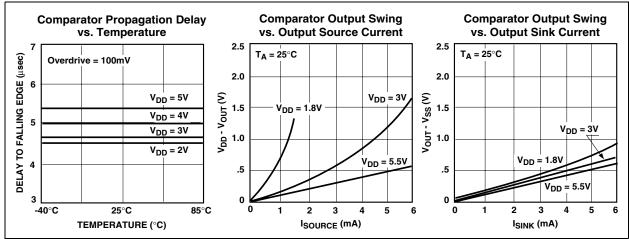
FIGURE 4-1: PRECISION BATTERY MONITOR

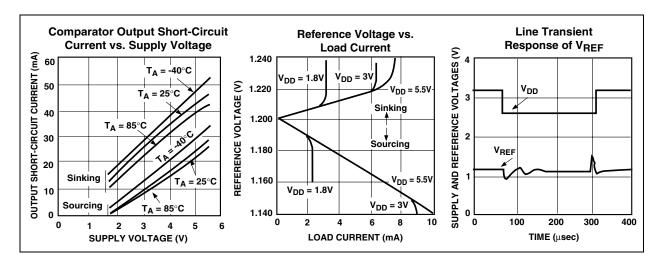


## 5.0 TYPICAL CHARACTERISTICS

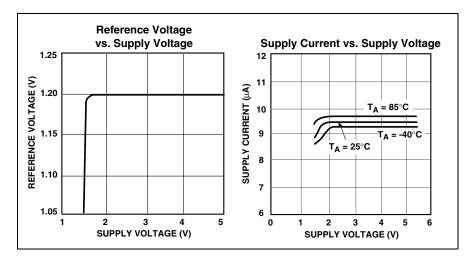
**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.







## 5.0 TYPICAL CHARACTERISTICS (CONTINUED)

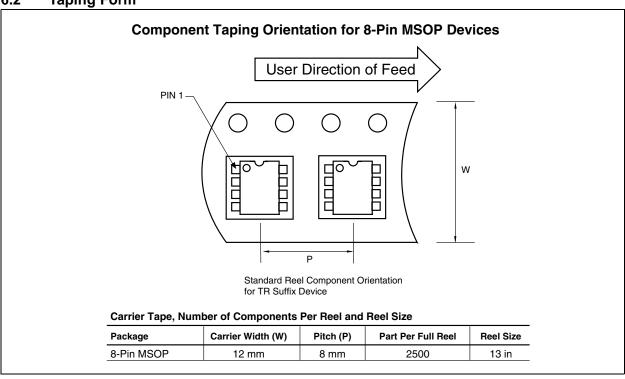


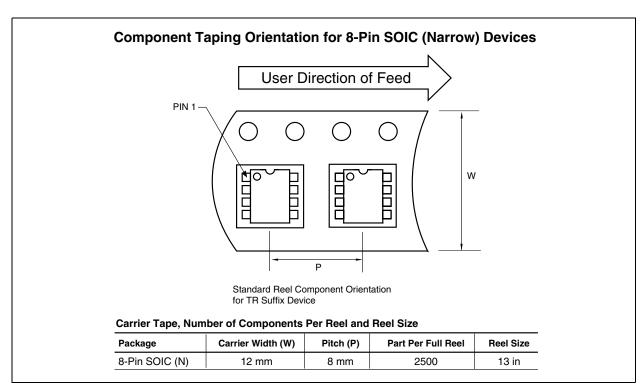
## 6.0 PACKAGING INFORMATION

## 6.1 Package Marking Information

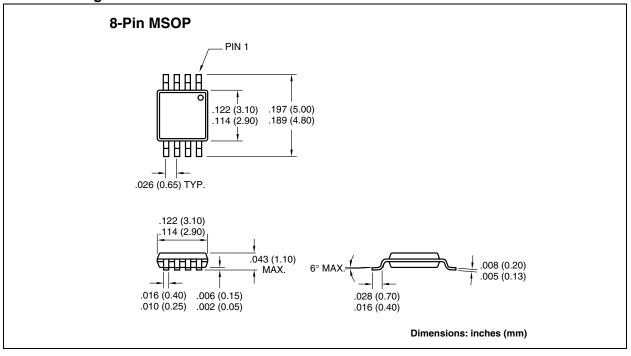
Package marking data not available at this time.

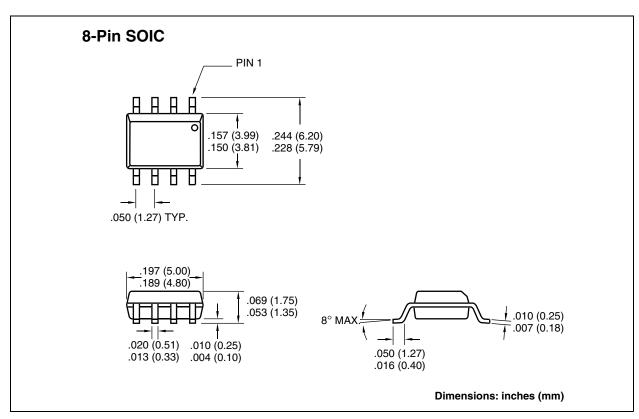
## 6.2 Taping Form





## 6.3 Package Dimensions





## TC1041

NOTES:

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